

PC923

High Speed Photocoupler for MOS-FET / IGBT Drive

* Lead forming type (I type) and taping reel type (P type) are also available. (PC923I/PC923P)

** TÜV (VDE 0884) approved type is also available as an option.

■ Features

1. Built-in direct drive circuit for MOS-FET/

IGBT drive

(I_{O1P} , I_{O2P} : 0.4A)

2. High speed response

(t_{PLH} , t_{PHL} : MAX. 0.5 μ s)

3. Wide operating supply voltage range

(V_{CC} : 15 to 30V, T_a = -10 to 60°C)

4. High noise reduction type

(CM_H = MIN. -1 500V/ μ s)

(CM_L = MIN. 1 500V/ μ s)

5. Recognized by UL, file No. E64380

6. High isolation voltage between input
and output (V_{ISO} = 5 000 V_{rms})

■ Applications

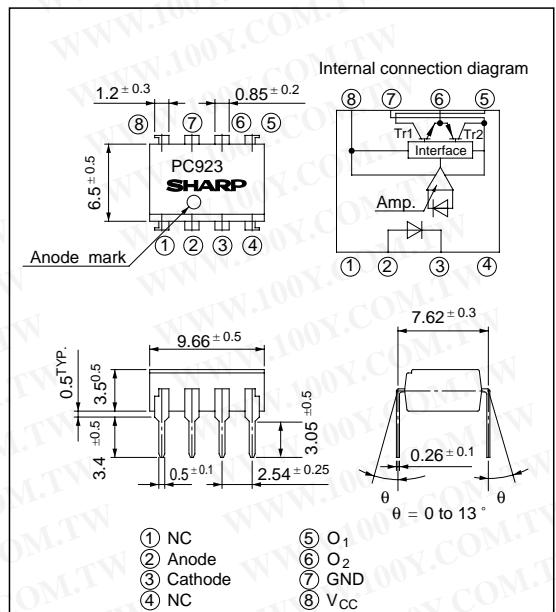
1. Inverter controlled air conditioners

勝特力材料 886-3-5753170
胜特力电子(上海) 86-21-54151736
胜特力电子(深圳) 86-755-83298787

[Http://www.100y.com.tw](http://www.100y.com.tw)

■ Outline Dimensions

(Unit : mm)



* "OPIC" (Optical IC) is a trademark of the SHARP Corporation.
An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

■ Absolute Maximum Ratings

(T_a = T_{opr} unless otherwise specified)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	20	mA
	*1 Reverse voltage	V_R	6	V
Output	Supply voltage	V_{CC}	35	V
	O_1 output current	I_1	0.1	A
	*2 O_1 peak output current	I_{O1P}	0.4	A
	O_2 output current	I_{O2}	0.1	A
	*2 O_2 peak output current	I_{O2P}	0.4	A
	O_1 output voltage	V_{O1}	35	V
	Power dissipation	P_O	500	mW
	Total power dissipation	P_{tot}	550	mW
	*3 Isolation voltage	V_{ISO}	5 000	V _{rms}
	Operating temperature	T_{opr}	-25 to +80	°C
	Storage temperature	T_{stg}	-55 to +125	°C
	Soldering temperature	T_{sol}	260	°C

*1 T_a = 25°C

*2 Pulse width <= 0.15 μ s,
Duty ratio: 0.01

*3 40 to 60% RH, AC for 1 minute,
 T_a = 25°C

*4 For 10 seconds

■ Electro-optical Characteristics

(Ta = T_{opr} unless otherwise specified)

Parameter		Symbol	*5 Conditions	MIN.	TYP.	MAX.	Unit	Fig.
Input	Forward voltage	V _{F1}	Ta = 25°C, I _F = 10mA	-	1.6	1.75	V	-
		V _{F2}	Ta = 25°C, I _F = 0.2mA	1.2	1.5	-	V	-
	Reverse current	I _R	Ta = 25°C, V _R = 5V	-	-	10	µA	-
Output	Terminal capacitance	C _t	Ta = 25°C, V = 0, f = 1MHz	-	30	250	pF	-
	Operating supply voltage	V _{CC}	Ta = -10 to 60°C	15	-	30	V	-
				15	-	24	V	
	O ₁ low level output voltage	V _{O1L}	V _{CC1} = 12V, V _{CC2} = -12V I _{O1} = 0.1A, I _F = 5mA	-	0.2	0.4	V	1
	O ₂ high level output voltage	V _{O2H}	V _{CC} = V _{O1} = 24V, I _{O2} = -0.1A, I _F = 5mA	18	21	-	V	2
	O ₂ low level output voltage	V _{O2L}	V _{CC} = 24V, I _{O2} = 0.1A, I _F = 0	-	1.2	2.0	V	3
	O ₁ leak current	I _{O1L}	Ta = 25°C, V _{CC} = V _{O1} = 35V, I _F = 0	-	-	500	µA	4
	O ₂ leak current	I _{O2L}	Ta = 25°C, V _{CC} = V _{O2} = 35V, I _F = 5mA	-	-	500	µA	5
Transfer characteristics	High level supply current	I _{CCH}	Ta = 25°C, V _{CC} = 24V, I _F = 5mA	-	6	10	mA	6
			V _{CC} = 24V, I _F = 5mA	-	-	14	mA	
	Low level supply current	I _{CCL}	Ta = 25°C, V _{CC} = 24V, I _F = 0	-	8	13	mA	6
			V _{CC} = 24V, I _F = 0	-	-	17	mA	
	*6 "Low→High" threshold input current	I _{FLH}	Ta = 25°C, V _{CC} = 24V	0.3	1.5	3.0	mA	7
			V _{CC} = 24V	0.2	-	5.0	mA	
	Isolation resistance	R _{ISO}	Ta = 25°C, DC = 500V, 40 to 60% RH	5 x 10 ¹⁰	10 ¹¹	-	Ω	-
	Response time	t _{PLH} , t _{PHL}	"Low→High" propagation delay time	Ta = 25°C, V _{CC} = 24V, I _F = 5mA	-	0.3	0.5	µs
			"High→Low" propagation delay time		-	0.3	0.5	µs
	Rise time	t _r			-	0.2	0.5	µs
	Fall time	t _f		R _C = 47Ω, C _G = 3000pF	-	0.2	0.5	µs
	Instantaneous common mode rejection voltage "Output : High level"	CH _M	Ta = 25°C, V _{CM} = 600V(peak) I _F = 5mA, V _{CC} = 24V, ΔV _{O2H} = 2.0V	-	-30	-	kV/µs	9
	Instantaneous common mode rejection voltage "Output : Low level"	CM _L	Ta = 25°C, V _{CM} = 600V(peak) I _F = 0, V _{CC} = 24V, ΔV _{O2L} = 2.0V	-	30	-	kV/µs	

*5 When measuring output and transfer characteristics, connect a by-pass capacitor (0.01 µF or more) between V_{CC} and GND near the PC923.

*6 I_{FLH} represents forward current when O₂ output goes from low to high.

■ Truth Table

Input	O ₂ Output	Tr. 1	Tr. 2
ON	High level	ON	OFF
OFF	Low level	OFF	ON

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■ Test Circuit

Fig. 1

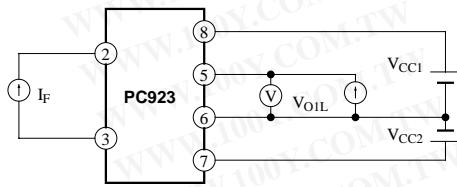


Fig. 3

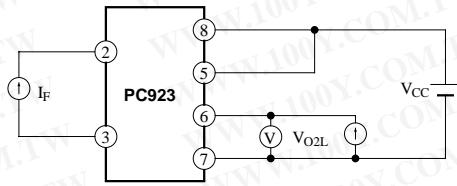


Fig. 5

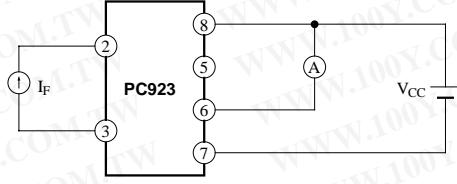


Fig. 7

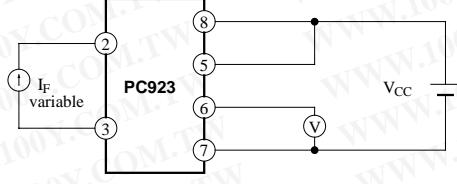


Fig. 9

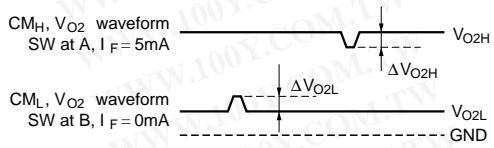
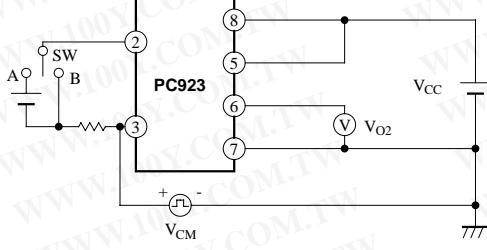


Fig. 2

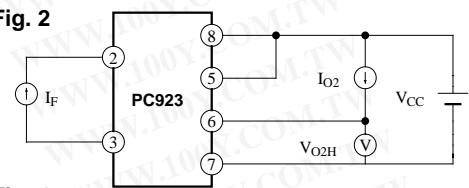


Fig. 4

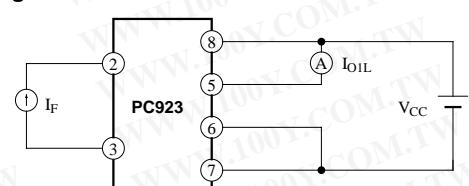


Fig. 6

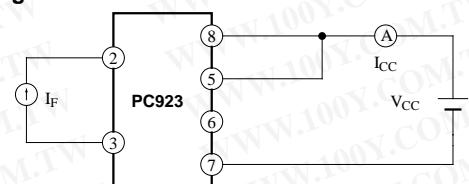
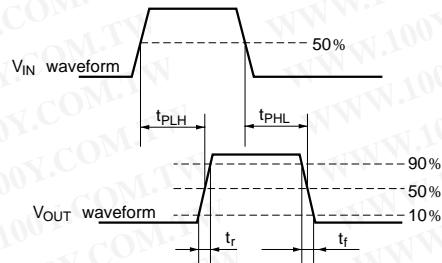
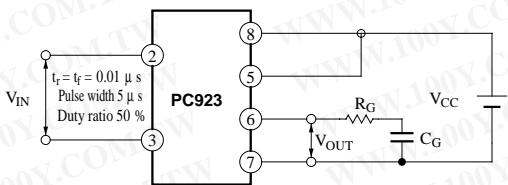


Fig. 8



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Fig.10 Forward Current vs. Ambient Temperature

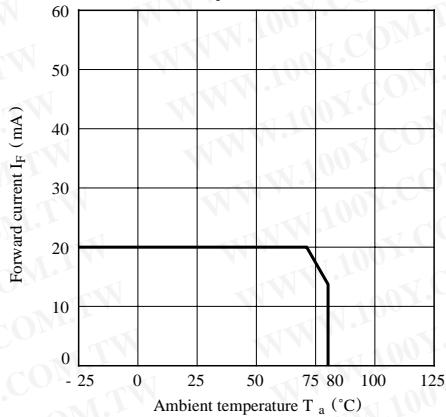


Fig.12 Forward Current vs. Forward Voltage

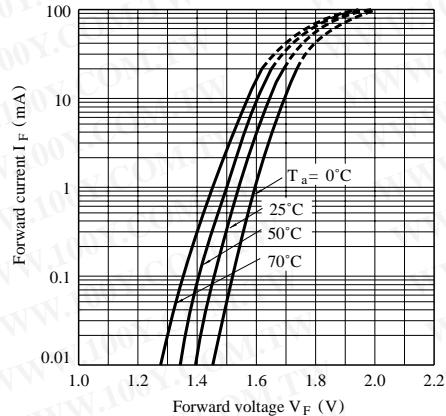


Fig.14 “Low→High” Relative Threshold Input Current vs. Ambient Temperature

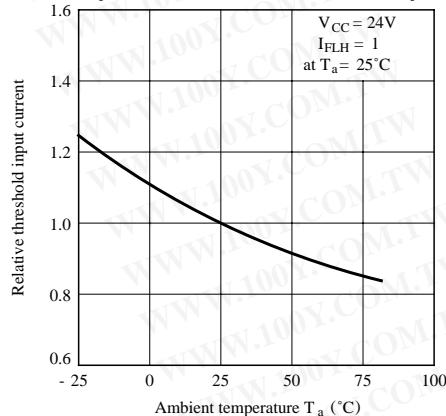


Fig.11 Power Dissipation vs. Ambient Temperature

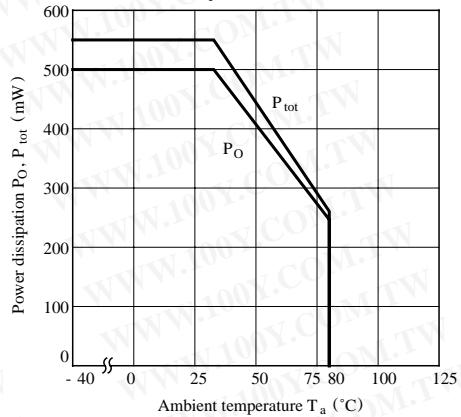


Fig.13 “Low→High” Relative Threshold Input Current vs. Supply Voltage

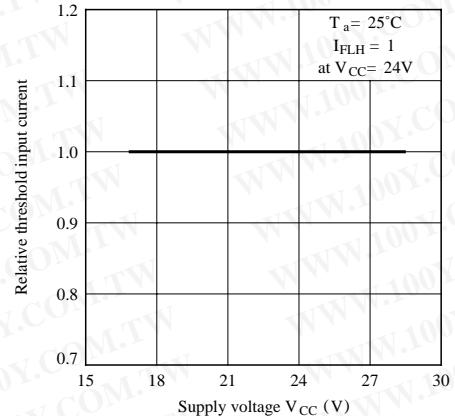


Fig.15 O₁ Low Level Output Voltage vs. O₁ Output Current

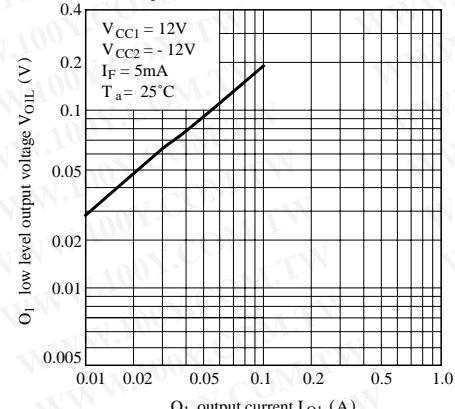


Fig.16 O₁ Low Level Output Voltage vs. Ambient Temperature

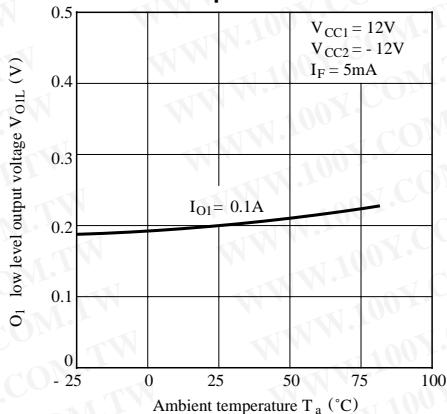


Fig.18 O₂ High Level Output Voltage vs. Ambient Temperature

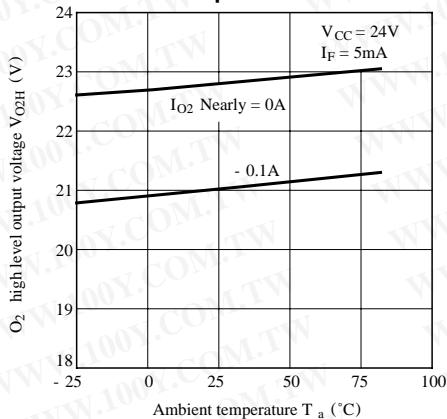


Fig.20 O₂ Low Level Output Voltage vs. Ambient Temperature

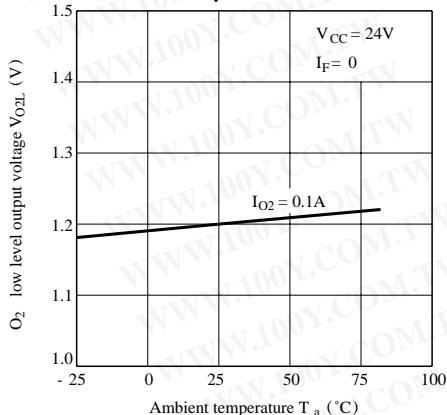


Fig.17 O₂ High Level Output Voltage vs. Supply Voltage

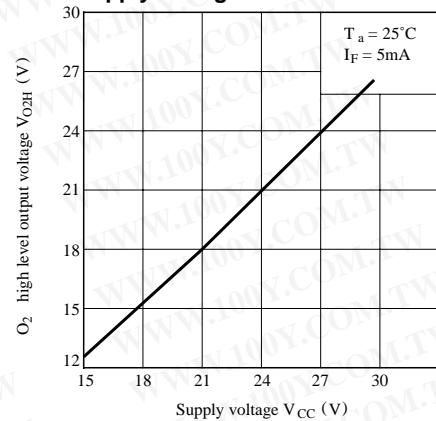


Fig.19 O₂ Low Level Output Voltage vs. O₂ Output Current

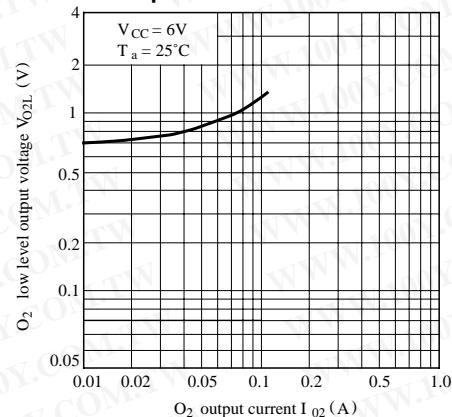
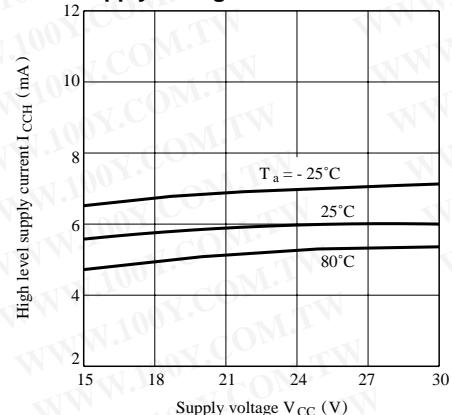
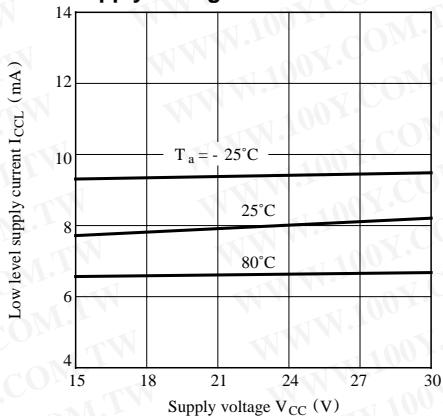


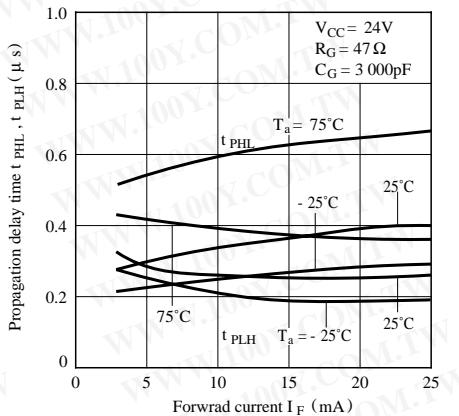
Fig.21 High Level Supply Current vs. Supply Voltage



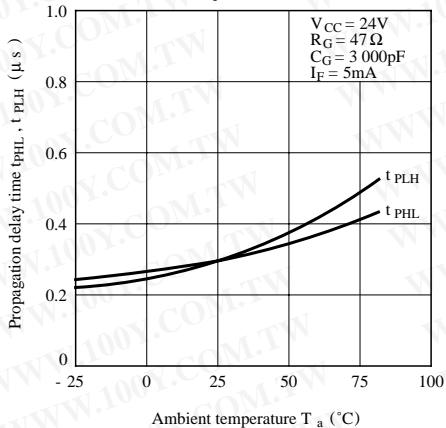
**Fig.22 Low Level Supply Current vs.
Supply Voltage**



**Fig.23 Propagation Delay Time vs.
Forward current**

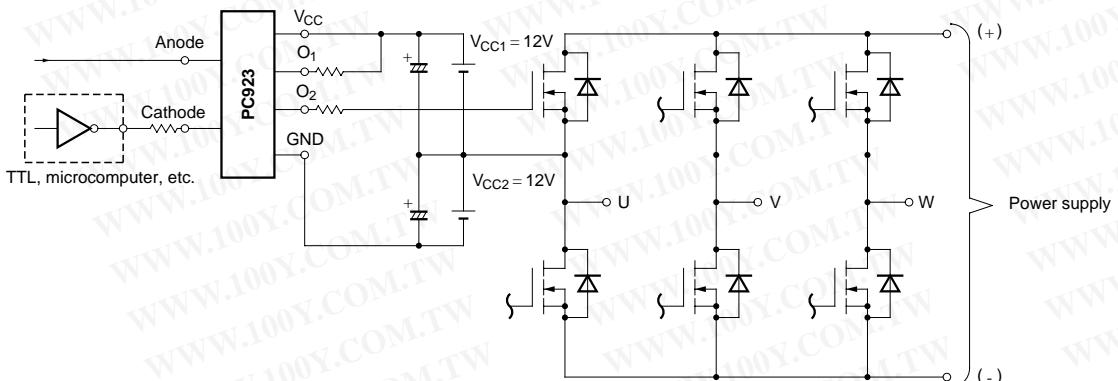


**Fig.24 Propagation Delay Time vs.
Ambient Temperature**



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■ Application Circuit (For Power MOS-FET Driving Inverter)



● Please refer to the chapter "Precautions for Use."